SN54LVTH2245, SN74LVTH2245 3.3-V ABT OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS707E - SEPTEMBER 1997 - REVISED OCTOBER 2003

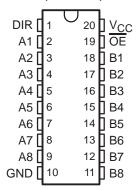
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- B-Port Outputs Have Equivalent 22-Ω
 Series Resistors, So No External Resistors
 Are Required
- I_{off} and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)

description/ordering information

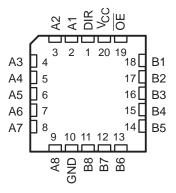
These octal bus transceivers are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices are designed for asynchronous communication between data buses. They transmit data from the A bus to the B bus or from

SN54LVTH2245 . . . J OR W PACKAGE SN74LVTH2245 . . . DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



SN54LVTH2245 . . . FK PACKAGE (TOP VIEW)



the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the devices so the buses are effectively isolated.

ORDERING INFORMATION

TA	PACKA	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
	0010 5111	Tube	SN74LVTH2245DW	1) (THOO 45		
–40°C to 85°C	SOIC - DW	Tape and reel	SN74LVTH2245DWR	LVTH2245		
	SOP - NS	Tape and reel	SN74LVTH2245NSR	LVTH2245		
	SSOP - DB	Tape and reel	SN74LVTH2245DBR	LK245		
		Tube	SN74LVTH2245PW	11/045		
	TSSOP – PW	Tape and reel	SN74LVTH2245PWR	LK245		
	TVSOP - DGV	Tape and reel	SN74LVTH2245DGVR	LK245		
	CDIP – J	Tube	SNJ54LVTH2245J	SNJ54LVTH2245J		
-55°C to 125°C	CFP – W	Tube	SNJ54LVTH2245W	SNJ54LVTH2245W		
	LCCC – FK	Tube	SNJ54LVTH2245FK	SNJ54LVTH2245FK		

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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SCBS707E - SEPTEMBER 1997 - REVISED OCTOBER 2003

description/ordering information (continued)

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

The B-port outputs, which are designed to source or sink up to 12 mA, include equivalent $22-\Omega$ series resistors to reduce overshoot and undershoot.

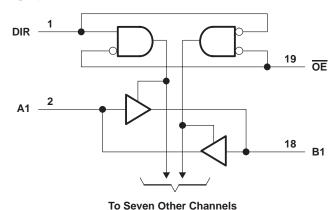
When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

FUNCTION TABLE

INP	UTS	0050471011
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation

logic diagram (positive logic)





SCBS707E - SEPTEMBER 1997 - REVISED OCTOBER 2003

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		
or power-off state, V _O (see Note 1)		
Voltage range applied to any output in the high Current into any output in the low state, I _O : SN		
	174LVTH2245 (A port)	
	port	
Current into any output in the high state, I _O (se		
	SN74LVTH2245 (A port)	
	B port	
Input clamp current, I_{IK} ($V_I < 0$)		
Output clamp current, I_{OK} ($V_O < 0$)		
Package thermal impedance, θ _{JA} (see Note 3):		
•	DGV package	92°C/W
	DW package	
	NS package	60°C/W
	PW package	
Storage temperature range, T _{stq}		

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4)

			SN54LVT	H2245	SN74LVT	H2245	
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		2.7	3.6	2.7	3.6	V
VIH	High-level input voltage		2		2		V
V _{IL}	Low-level input voltage			0.8		0.8	V
VI	Input voltage			5.5		5.5	V
	Likely level and and annual	A port	,	-24		-32	A
Іон	High-level output current	B port	6	-12		mA	
	Law lavel autout aumout	A port	22	48		64	A
lOL	Low-level output current	B port	20,70	12		12	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q	10		10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200		200		μs/V
T _A	Operating free-air temperature	·	-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SN54LVTH2245, SN74LVTH2245 3.3-V ABT OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS707E - SEPTEMBER 1997 - REVISED OCTOBER 2003

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAE	AMETER	TEOT 00	NIDITIONS	SN5	4LVTH2	245	SN7	4LVTH2	245	LINUT
PAR	RAMETER	TEST CC	ONDITIONS	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT
٧ıK		$V_{CC} = 2.7 \text{ V},$	$I_I = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100 \mu A$	VCC-0	.2		VCC-0	.2		
	A nort	$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			
V	A port	V 2.V	$I_{OH} = -24 \text{ mA}$	2						V
VOH		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2			V
	D nort	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100 \mu A$	V _{CC} -0	.2		V _{CC} -0	.2		
	B port	$V_{CC} = 3 V$,	$I_{OH} = -12 \text{ mA}$	2			2			
		\/ 27\/	$I_{OL} = 100 \mu A$			0.2			0.2	
		V _{CC} = 2.7 V	I _{OL} = 24 mA			0.5			0.5	
	A nort		I _{OL} = 16 mA			0.4			0.4	
V	A port	\\\\\\\\\\\\	$I_{OL} = 32 \text{ mA}$			0.5		0.5		
VOL		VCC = 3 V	$I_{OL} = 48 \text{ mA}$			0.55				V
			$I_{OL} = 64 \text{ mA}$						0.55	
	D nort	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	I_{OL} = 100 μ A	0.2			0.2			
	B port	$V_{CC} = 3 V$,	$I_{OL} = 12 \text{ mA}$			0.8			8.0	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND		Q	±1			±1	
		$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V		Ç	10			10	
lį		V _{CC} = 3.6 V	V _I = 5.5 V		20				20	μΑ
	A or B ports‡		VI = VCC	Q.				1		
			V _I = 0			-5			-5	
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V						±100	μΑ
		\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	V _I = 0.8 V	75			75			
l(hold)	A or B ports	VCC = 3 V	V _I = 2 V	-75			-75			μΑ
'I(noia)	/ or B ports	V _{CC} = 3.6 V§,	$V_I = 0$ to 3.6 V					-1.2 C-0.2 2.4 2 C-0.2 2 0.2 0.5 0.4 0.5 0.5 0.2 0.8 ±1 10 20 1 -5 ±100 75 75 500 -750 ±100 0.1 0.19 3 5 0.1 0.19	500 -750	μπ
lozpu		$\frac{V_{CC}}{OE} = 0$ to 1.5 V, $V_{O} =$	0.5 V to 3 V,			±100*			±100	μА
l _{OZPD}		$\frac{\text{V}_{\text{CC}}}{\text{OE}} = 1.5 \text{ V to 0, V}_{\text{O}} =$	0.5 V to 3 V,			±100*			±100	μА
		V _{CC} = 3.6 V,	Outputs high			0.19		0.1	0.19	
ICC		IO = 0	Outputs low			5		3	5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19		0.1	0.19	
ΔICC¶		V _{CC} = 3 V to 3.6 V, One Other inputs at V _{CC} or				0.2			0.2	mA
Ci		V _I = 3 V or 0			4			4		pF
C _{io}		V _O = 3 V or 0			9			9		pF
										<u> </u>

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] Unused terminals are at V_{CC} or GND.

[§] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

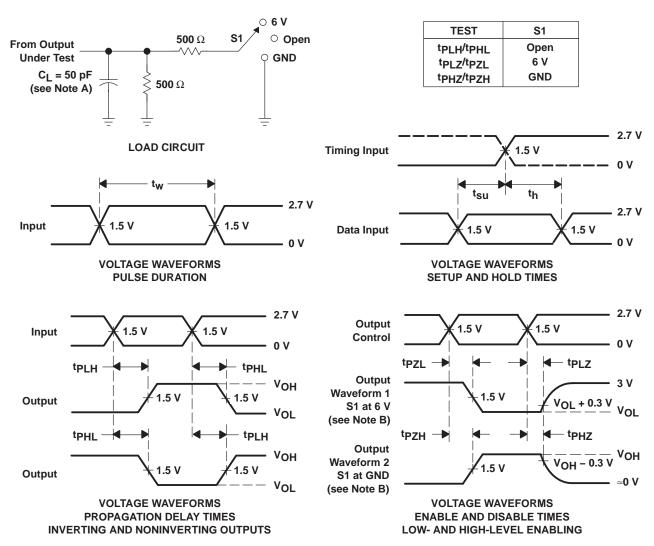
 $[\]P$ This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

				SN54LV	TH2245			SN7	4LVTH2	245		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V			V _{CC} = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
tPLH .	А	В	1	4.6		5.3	1.1	2.9	4.4		5.1	20
^t PHL	A	Ь	1	4.6		5.3	1.1	2.6	4.4		5.1	ns
^t PLH	В	^	1	3.7	2	4.2	1.1	2.2	3.5		4	20
t _{PHL}		Α	1	3.7		4.2	1.1	2	3.5		4	ns
^t PZH	ŌĒ	А	1.2	5.7	176	7.4	1.3	3.1	5.5		7.1	
t _{PZL}	OE		1.6	5.7	2	6.8	1.7	3.2	5.5		6.5	ns
^t PHZ	<u>OE</u>	А	2	6.2		6.8	2.2	3.6	5.9		6.5	ns
t _{PLZ}	ÖL	X	2	5.3		5.5	2.2	3.4	5		5.1	115
^t PZH	ŌĒ		1.2	6.4		7.6	1.3	3.5	6.2		7.3	
tPZL	OE	В	1.6	6.4		7.5	1.7	3.7	6.2		7.3	ns
^t PHZ	ŌĒ	В	2	6.1		6.8	2.2	3.9	5.9		6.5	20
tPLZ	OE .	D	2	5.7		5.9	2.2	3.7	5.4		5.7	ns

 $[\]uparrow$ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50~\Omega$, $t_f \leq 2.5~\text{ns}$, $t_f \leq 2.5~\text{ns}$.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74LVTH2245DBR	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245DBR.B	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245DGVR	Active	Production	TVSOP (DGV) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245DGVR.B	Active	Production	TVSOP (DGV) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245DW	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH2245
SN74LVTH2245DW.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH2245
SN74LVTH2245DWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH2245
SN74LVTH2245DWR.B	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH2245
SN74LVTH2245PW	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245PW.B	Active	Production	TSSOP (PW) 20	70 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245PWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245PWR.B	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245
SN74LVTH2245PWRG4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LK245

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH2245DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH2245DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVTH2245DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVTH2245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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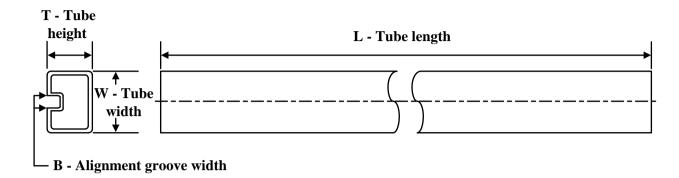
*All dimensions are nominal

Device	Package Type	Package Drawing	ge Drawing Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
SN74LVTH2245DBR	SSOP	DB	20	2000	353.0	353.0	32.0	
SN74LVTH2245DGVR	TVSOP	DGV	20	2000	353.0	353.0	32.0	
SN74LVTH2245DWR	SOIC	DW	20	2000	356.0	356.0	45.0	
SN74LVTH2245PWR	TSSOP	PW	20	2000	353.0	353.0	32.0	

PACKAGE MATERIALS INFORMATION

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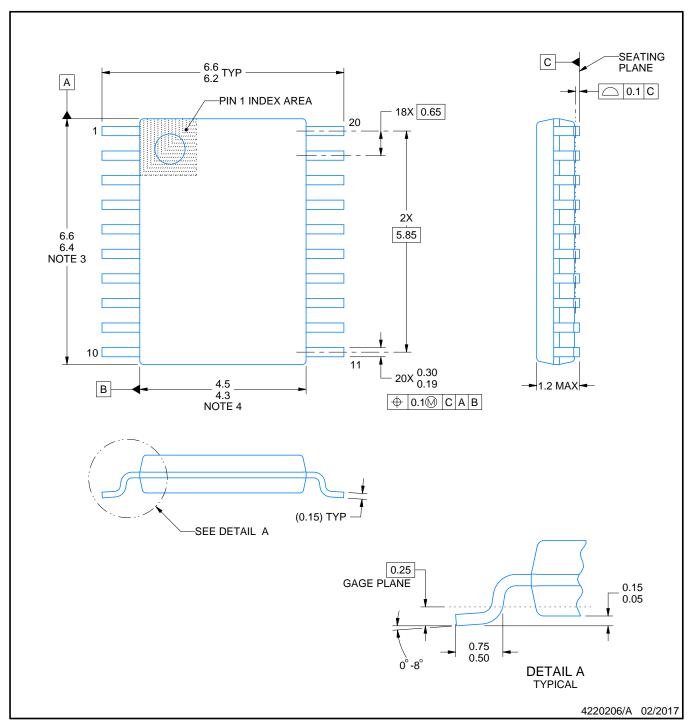
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LVTH2245DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH2245DW.B	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH2245PW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVTH2245PW.B	PW	TSSOP	20	70	530	10.2	3600	3.5





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







NOTES:

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- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

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- 9. Board assembly site may have different recommendations for stencil design.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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